## **AMENDMENTS TO THE CLAIMS**

Docket No.: 14113-00041-US

- 1. (Original) Single-phase, liquid compositions (solutions) comprising
- at least one organic semiconductor which comprises at least one high-molecular-weight component,
- and at least one organic solvent A,
- and at least one organic solvent B,
- and at least one organic solvent C,

## characterised in that

- solvent A is a good solvent for the organic semiconductor,
- solvent B is a good solvent for the organic semiconductor,
- solvent C is a poor solvent for the organic semiconductor and
- the following applies to the boiling points (b.p.) of solvents A, B and C: b.p.(A) < b.p.(C) < b.p.(B), and/or to the respective partial vapour pressures (p) at the temperature of the coating methods of solvents A, B and C: p(A) > p(C) > p(B).
- 2. (Original) Solutions according to Claim 1, characterised in that the organic semiconductor is soluble in the pure solvent A or in the pure solvent B in a concentration of at least 5 g/l at room temperature.
- 3. (Currently amended) Solutions according to Claims 1 and/or 2 claim 1, characterised in that the solubility of the organic semiconductor in the pure solvent C at room temperature is less than 0.3 g/l.
- 4. (Currently amended) Solutions according to one or more of Claims 1-to 3 claim 1, characterised in that the organic semiconductor is employed as pure component.

- 5. (Currently amended) Solutions according to one or more of Claims 1 to 3 claim 1, characterised in that the organic semiconductor is employed as a mixture of two or more components.
- 6. (Original) Solutions according to Claim 5, characterised in that one or more organic non-conductors are used as matrix.

Docket No.: 14113-00041-US

- 7. (Currently amended) Solutions according to one or more of Claims 1 to 6 claim 1, characterised in that the high-molecular-weight component has a molecular weight  $M_w$  of greater than 50,000 g/mol.
- 8. (Currently amended) Solutions according to one or more of Claims 1 to 7 claim 1, characterised in that the polymeric organic semiconductors employed are substituted poly-paraylenevinylenes (PAVs), polyfluorenes (PFs), polyspirobifluorenes (PSFs), poly-paraphenylenes (PPPs) or -biphenylenes, polydihydrophenanthrenes (PDHPs), cis- and transpolyindenofluorenes (PIFs), polythiophenes (PTs), polypyridines (PPys), copolymers which contain structural units from two or more of the above-mentioned classes, generally conjugated polymers, polyvinylcarbazoles (PVKs), polytriarylamines and/or soluble polymers containing phosphorescent units, which are soluble in organic solvents.
- 9. (Currently amended) Solutions according to one or more of Claims 1 to 8 claim 1, characterised in that non-conducting polymers (matrix polymers) which comprise low-molecular-weight, oligomeric, dendritic or polymeric organic and/or organometallic semiconductors are used.
- 10. (Currently amended) Solutions according to one or more of Claims 1 to 9 claim 1, characterised in that the boiling point of all three solvents A, B and C is greater than 120°C.
- 11. (Currently amended) Solutions according to one or more of Claims 1 to 10 claim 1, characterised in that the boiling point of all three solvents A, B and C is less than 300°C.
- 12. (Currently amended) Solutions according to one or more of Claims 1 to 11 claim 1, characterised in that the difference between the boiling points of solvent A and solvent C is greater than 10 K.

13. (Currently amended) Solutions according to one or more of Claims 1 to 12 claim 1, characterised in that the difference between the boiling points of solvent C and solvent B is greater than 10 K.

Docket No.: 14113-00041-US

- 14. (Currently amended) Solutions according to one or more of Claims 1 to 13 claim 1, characterised in that the proportion of solvent A is 10 to 80% by vol., the proportion of solvent B is 0.5 to 40% by vol. and the proportion of solvent C is 10 to 90% by vol.
- 15. (Original) Solutions according to Claim 14, characterised in that the proportion of solvent A is 25 to 60% by vol., the proportion of solvent B is 2 to 20% by vol. and the proportion of solvent C is 30 to 70% by vol.
- 16. (Currently amended) Solutions according to one or more of Claims 1 to 15 claim 1, characterised in that other good and/or poor solvents are used in addition to solvents A, B and C.
- 17. (Currently amended) Solutions according to one or more of Claims 1 to 16 claim 1, characterised in that solvents A and/or B used are mono- or polysubstituted aromatic solvents, formic acid derivatives, N-alkylpyrrolidones or high-boiling ethers.
- 18. (Original) Solutions according to Claim 17, characterised in that solvents A and/or B are one or more solvents selected from 3-fluorobenzotrifluoride, benzotrifluoride, dioxane, trifluoromethoxybenzene, 4-fluorobenzotrifluoride, 3-fluoropyridine, toluene, 2-fluorotoluene, 2-fluorobenzotrifluoride, 3-fluorotoluene, pyridine, 4-fluorotoluene, 2,5-difluorotoluene, 1-chloro-2,4-difluorobenzene, 2-fluoropyridine, 3-chlorofluorobenzene, 1-chloro-2,5-difluorobenzene, 4-chlorofluorobenzene, chlorobenzene, 2-chlorofluorobenzene, p-xylene, m-xylene, o-xylene, 2,6-lutidine, 2-fluoro-m-xylene, 3-fluoro-o-xylene, 2-chlorobenzotrifluoride, dimethylformamide, 2-chloro-6-fluorotoluene, 2-fluoroanisole, anisole, 2,3-dimethylpyrazine, bromobenzene, 4-fluoroanisole, 3-fluoroanisole, 3-trifluoromethylanisole, 2-methylanisole, phenetol, benzodioxole, 4-methylanisole, 3-methylanisole, 4-fluoro-3-methylanisole, 1,2-dichlorobenzene, 2-fluorobenzonitrile, 4-fluoroveratrol, 2,6-dimethylanisole, aniline, 3-fluorobenzonitrile, 2,5-dimethylanisole, 2,4-dimethylanisole, benzonitrile, 3,5-dimethylanisole, N,N-dimethylaniline, 1-fluoro-3,5-dimethoxybenzene, phenyl acetate, N-methylaniline, methyl benzoate, N-methylpyrrolidone, 3,4-dimethylanisole, acetophenone, o-tolunitrile, 4-tert-480997

butylanisole, veratrol, ethyl benzoate, N,N-diethylaniline, propyl benzoate, 1-methylnaphthalene, 3,5-dimethoxytoluene, butyl benzoate, 2-methylbiphenyl, dimethylnaphthalene, 2-phenylpyridine or 2,2'-bitolyl.

Docket No.: 14113-00041-US

- 19. (Currently amended) Solutions according to one or more of Claims 1 to 18 claim 1, characterised in that the solvents C used are straight-chain, branched or cyclic higher alkanes, preferably having seven or more C atoms, terpenes, (cyclo)aliphatic alcohols, ketones, carboxylic acid esters or mono- or polysubstituted aromatic solvents which are substituted by long alkyl or alkoxy substituents having 4 or more C atoms, higher alcohols having more than 4 C atoms, glycols or ethers thereof.
- 20. (Original) Solutions according to Claim 19, characterised in that at least one solvent C is selected from methylcyclohexane, 3-pentanol, 1,4-dimethylcyclohexane, ethylene glycol monomethyl ether, 1,2-dimethylcyclohexane, octane, 2-hexanol, 1-pentanol, 1,2,4-trimethylcyclohexane, 4-heptanone, 3-heptanone, 2-heptanone, nonane, cyclohexanone, 3-heptanol, 1-hexanol, 2-heptanol, diglyme, butyl butyrate, tert-butylbenzene, decane, 1-heptanol, 2-octanol, butylcyclohexane, 2-ethyl-1-hexanol, decalin, propylene glycol, dimethyl sulfoxide, 3,3,5-trimethylcyclohexanone, glycol, 3,7-dimethyl-1-octanol, 3,7-dimethyl-3-octanol, dimethyl succinate, tert-butyl-m-xylene, benzyl alcohol, DBE, dodecane, diethyl succinate, triglyme, bicyclohexyl, dimethyl adipate, 1-decanol or 2-pyrrolidone.
- 21. (Currently amended) Use of solutions according to one or more of Claims 1 to 20 claim

  1 for the production of layers of the organic semiconductors on a substrate.
- 22. (Currently amended) Process for the production of organic semiconductor layers on a substrate, characterised in that a solution according to <u>claim 1 one or more of Claims 1 to 20</u> is processed by means of a printing method.
- 23. (Original) Process according to Claim 22, characterised in that the printing method is an ink-jet printing (IJP) method.

Application No. National Phase of PCT/EP2005/001596 First Preliminary Amendment

24. (Currently amended) Layers of organic semiconductors, characterised in that they are produced using a solution the solution according to claim 1 one or more of Claims 1 to 20 or by means of a printing method according to Claim 22 and/or 23.

Docket No.: 14113-00041-US

- 25. (Original) Polymeric light-emitting diodes (PLEDs), organic field-effect transistors (O-FETs), organic thin-film transistors (O-TFTs), organic integrated circuits (O-ICs), organic solar cells (O-SCs) or organic laser diodes (O-lasers) comprising at least one layer according to Claim 24.
- 26. (New) Layers of organic semiconductors, characterised in that they are produced by means of the printing method according to Claim 22.